Single Supply Quad Operational Amplifier with Full Swing Output

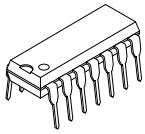
■GENERAL DESCRIPTION

The NJM2747 is a quad low supply voltage operational amplifier with Full swing output.

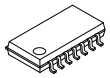
The output full swing function provides wide dynamic range, is from ground to power supply level. And Input range rails from ground level.

It is suitable for audio section of portable sets, PCs and any General-purpose use.

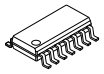
■PACKAGE OUTLINE



NJM2747D



NJM2747M



NJM2747E

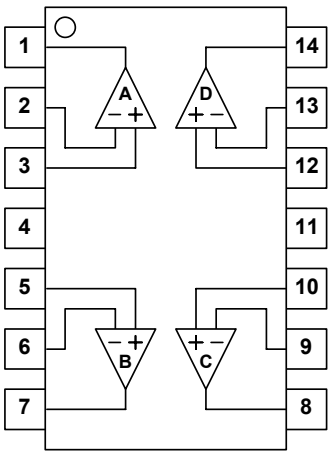
NJM2747V

■ FEATURES

●Operating Voltage	2.5V to 14V
●Output Full Swing	V_{OH} ≥4.9V Typ. (at V^+=5V, R_L=5kΩ)
	V_{OL} ≤0.1V Typ. (at V^+=5V, R_L=5kΩ)
●Offset Voltage	1mV Typ
●Slew Rate	3.5V/μs Typ.
●Low Distortion	0.001% typ. (at V^+=5V, f=1kHz)
●Low Input Voltage Noise	10nV/√Hz typ.
●Bipolar Technology	
●Package Outline	NJM2747D DIP14
	NJM2747M DMP14
	NJM2747E EMP14
	NJM2747V SSOP14

■ PIN CONFIGURATION

(Top View)



PIN FUNCTION

1. OUTPUT A	8. OUTPUT C
2. −INPUT A	9. −INPUT C
3. +INPUT A	10. +INPUT C
4. V^+	11. GND
5. +INPUT B	12. +INPUT D
6. −INPUT B	13. −INPUT D
7. OUTPUT B	14. OUTPUT D

■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V^+	15	V
Differential Input Voltage Range	V_{ID}	±15 (Note1)	V
Common Mode Input Voltage Range	V_{ICM}	0 to 15 (Note1)	V
Power Dissipation	P_D	DIP14 870 DMP14 450(Note2) EMP14 720(Note2) 1200(Note4) SSOP14 420(Note2) 520(Note4)	mW
Operating Temperature Range	T_{opr}	-40 to +85	˚C
Storage Temperature Range	T_{stg}	-50 to +125	˚C

(Note1) For supply voltage less than 15V, the absolute maximum input voltage is equal to the supply voltage.

(Note2) On the PCB " EIA/JEDEC (76.2×114.3×1.6mm, two layers, FR-4) "

(Note3) On the PCB " EIA/JEDEC (76.2×114.3×1.6mm, four layers, FR-4) "

■ OPERATING VOLTAGE (Ta=25˚C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V^+	2.5 to 14	V

■ ELECTRICAL CHARACTERISTICS

●DC CHARACTERISTICS (V^+=5V,Ta=25˚C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Current	I_{CC}	R_L=∞, V_{IN}=2.5V, No Signal Apply	-	8	11	mA
Input Offset Voltage	V_{IO}	R_S ≤ 10kΩ	-	1	6	mV
Input Bias Current	I_B		-	100	350	nA
Input Offset Current	I_{IO}		-	5	100	nA
Large Signal Voltage Gain	A_V	R_L≥10kΩ to 2.5V, Vo=0.5V to 4.5V	65	85	-	dB
Common Mode Rejection Ratio	CMR	0V ≤ V_{CM} ≤ 4V	60	75	-	dB
Supply Voltage Rejection Ratio	SVR	V^+=2.5V to 14V	60	80	-	dB
Output Voltage	V_{OH}	R_L=5kΩ to 2.5V	4.75	4.9	-	V
	V_{OL}	R_L=5kΩ to 2.5V	-	0.1	0.25	V
Input Common Mode Voltage Range	V_{ICM}	CMR ≥ 60dB	0	-	4	V

●AC CHARACTERISTICS (V^+=5V,Ta=25˚C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Unity Gain Bandwidth	GB	f=10kHz	-	10	-	MHz
Phase Margin	Φ_M	R_L=10kΩ, C_L=10pF	-	75	-	Deg
Equivalent Input Noise Voltage	V_{NI}	f=1kHz, V_{CM}=2.5V	-	10	-	nV/√Hz
Total Harmonic Distortion	THD	f=1kHz, A_V=+2 R_L=10kΩ to 2.5V, Vo=1.5Vrms	-	0.001	-	%
Amp to Amp Separation	CS	f=1kHz R_L=10kΩ to 2.5V, Vo=1.5Vrms	-	120	-	dB

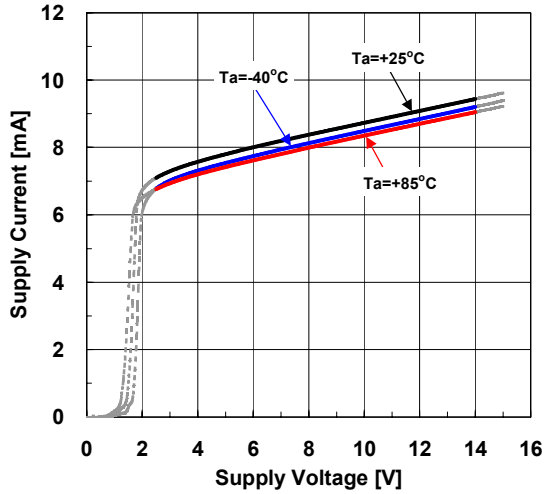
●AC CHARACTERISTICS (V^+=5V,Ta=25˚C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Slew Rate	SR	(Note 4), A_V=1, V_{IN}=2Vpp R_L=10kΩ to 2.5V C_L=10pF to 2.5V	-	3.5	-	V/μs

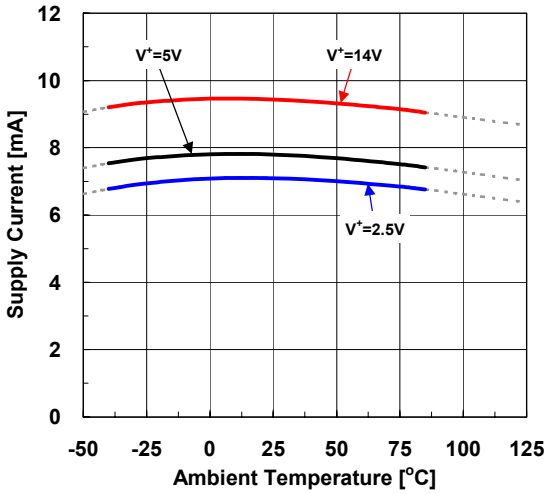
(Note 4) Number specified is the slower of the positive and negative slew rates.

■ TYPICAL CHARACTERISTICS

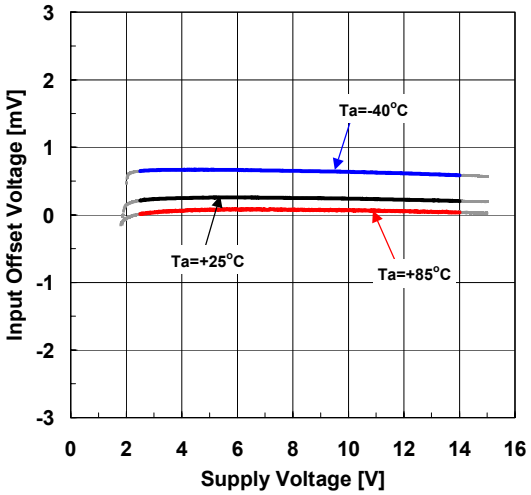
Supply Current vs. Supply Voltage
(Temperature)
G_V=0dB



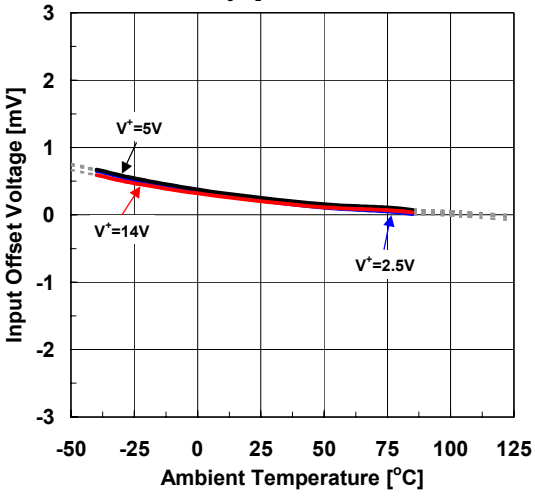
Supply Current vs. Ambient Temperature
(Supply Voltage)
G_V=0dB



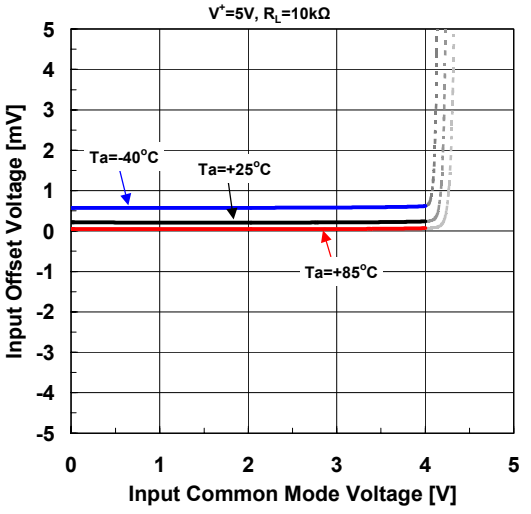
Input Offset Voltage vs. Supply Voltage
(Temperature)
R_S=R_L=10kΩ



Input Offset Voltage
vs. Ambient Temperature
(Supply Voltage)
R_S=R_L=10kΩ

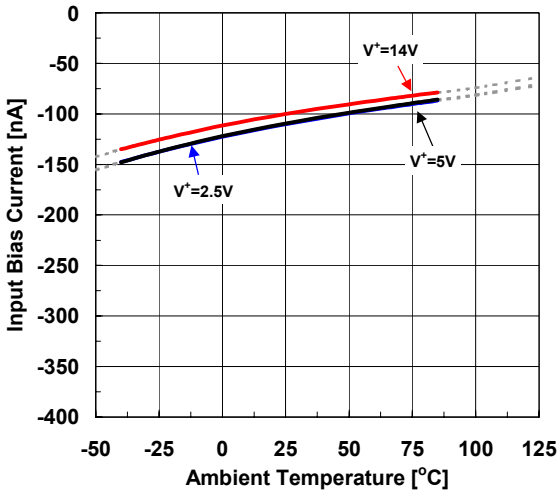


Input Offset Voltage
vs. Input Common Mode Voltage
(Temperature, V^+=5V)
V^+=5V, R_L=10kΩ

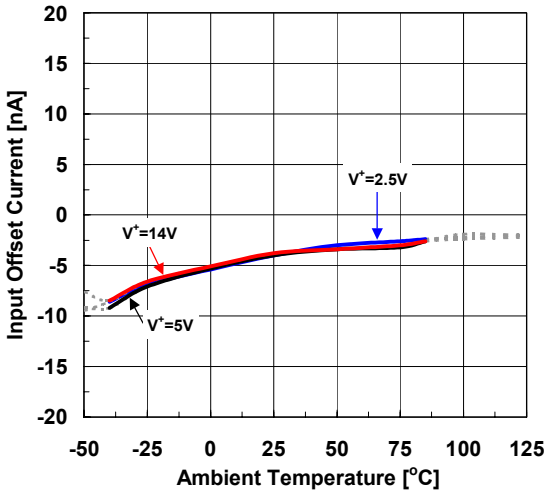


■ TYPICAL CHARACTERISTICS

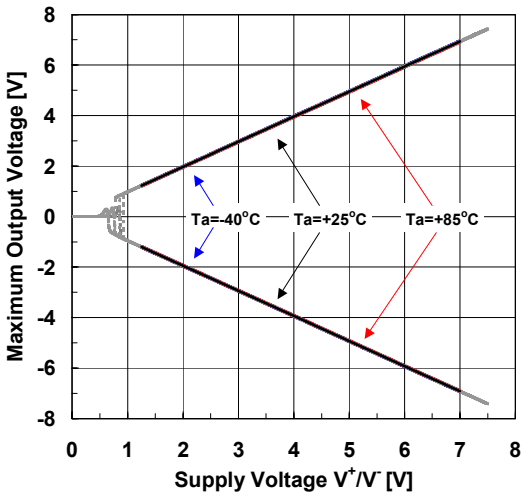
Input Bias Current vs. Ambient Temperature
(Supply Voltage)
R_L=10kΩ



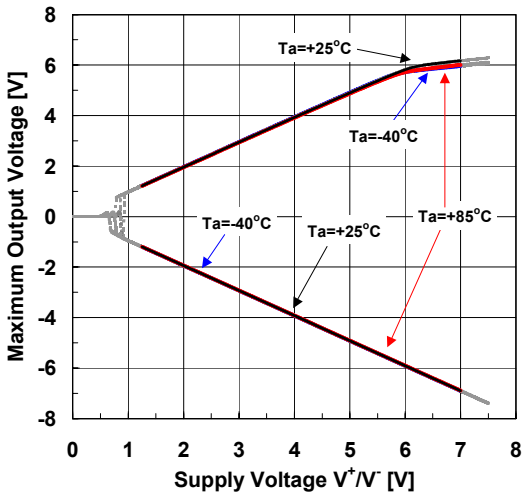
Input Offset Current
vs. Ambient Temperature (Supply Voltage)
R_L=10kΩ



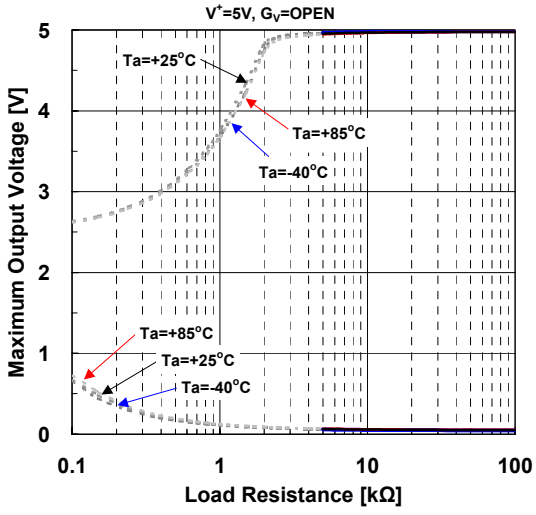
Maximum Output Voltage vs. Supply Voltage
(Temperature, R_L=10kΩ)
G_V=OPEN, R_L=10kΩ



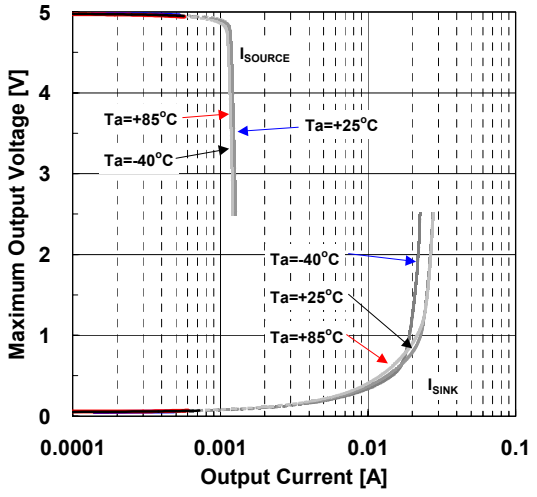
Maximum Output Voltage vs. Supply Voltage
(Temperature, R_L=5kΩ)
G_V=OPEN, R_L=10kΩ



Maximum Output Voltage
vs. Load Resistance
(Temperature, V+=5V)
V+=5V, G_V=OPEN

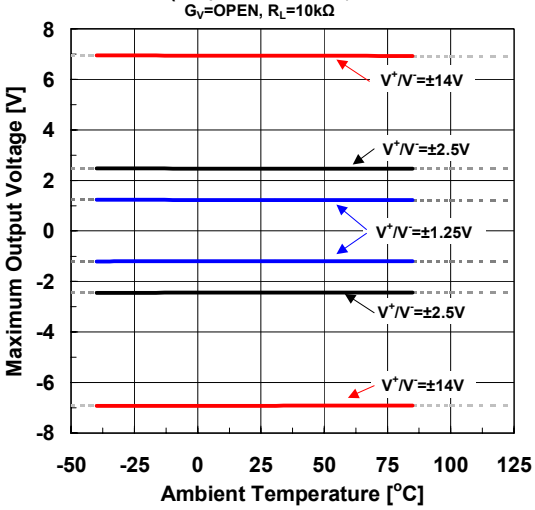


Maximum Output Voltage vs. Output Current
(Temperature, V+=5V)
V+=5V, G_V=OPEN

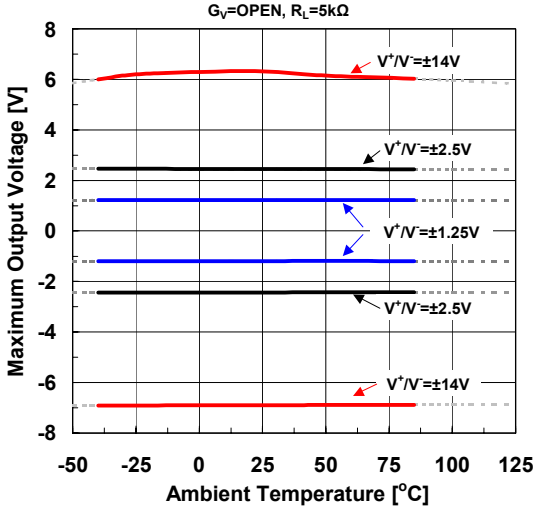


■ TYPICAL CHARACTERISTICS

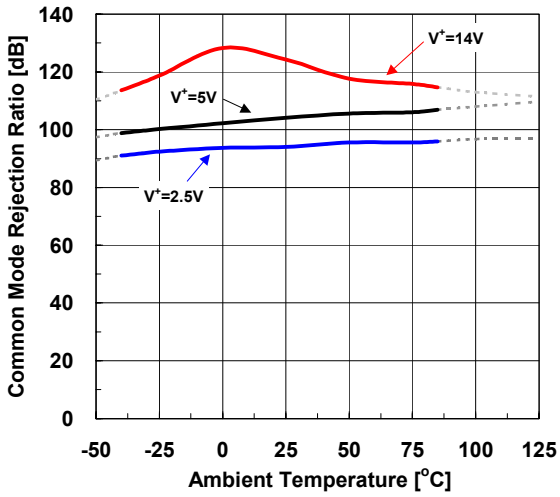
Maximum Output Voltage
vs. Ambient Temperature
(Temperature, R_{L}=10kΩ)
G_V=OPEN, R_L=10kΩ



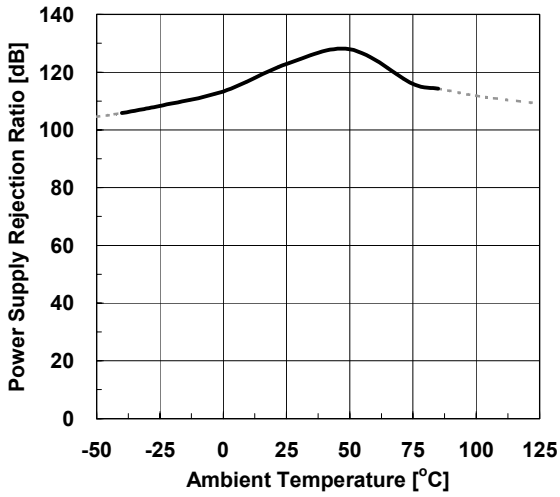
Maximum Output Voltage
vs. Ambient Temperature
(Temperature, R_L=5kΩ)
G_V=OPEN, R_L=5kΩ



Common Mode Rejection Ratio
vs. Ambient Temperature (Supply Voltage)
R_L=10kΩ, 0V ≤ V_{ICM} ≤ V^+-1V



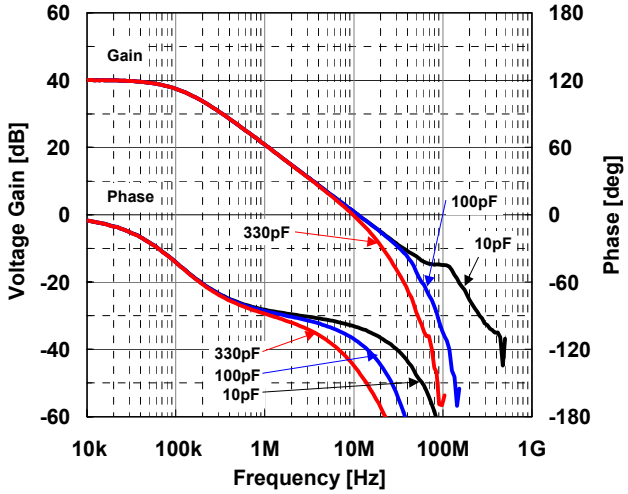
Power Supply Rejection Ratio
vs. Ambient Temperature
R_L=10kΩ, 2.5V ≤ V^+ ≤ 14V



■ TYPICAL CHARACTERISTICS

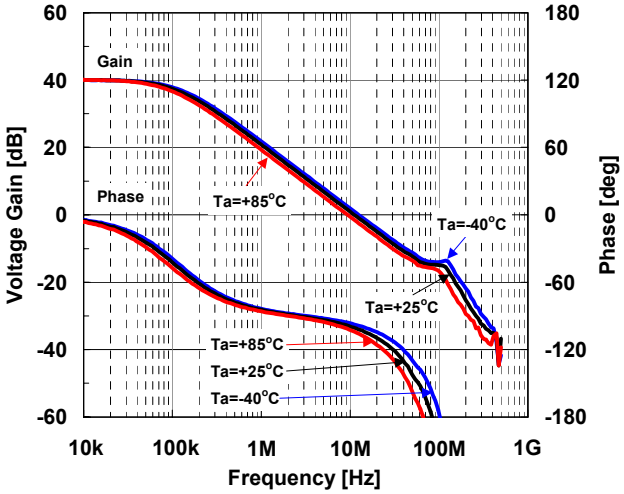
Gain/Phase vs. Frequency (Load Capacitance)

V^+=5V, V_{IN}=-30dBm, G_V=40dB, R_T=50Ω,
R_F=10kΩ, R_G=100Ω, Ta=+25°C



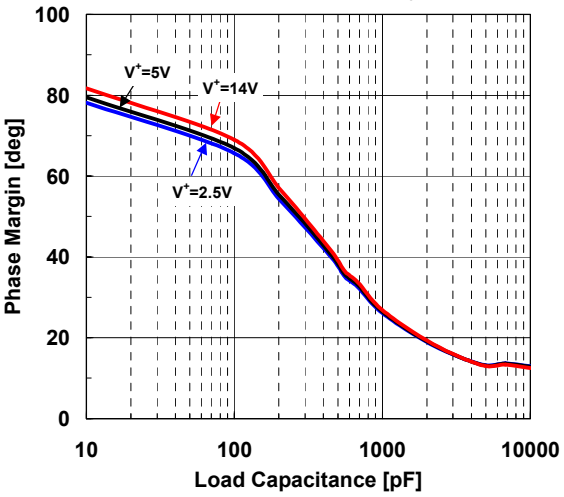
Gain/Phase vs. Frequency (Temperature)

V^+=5V, V_{IN}=-30dBm, G_V=40dB, R_T=50Ω,
R_F=10kΩ, R_G=100Ω, C_L=10pF



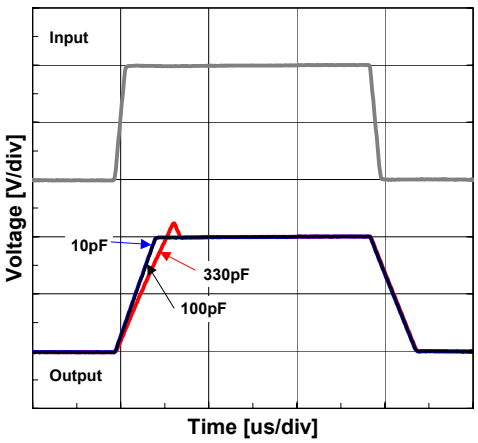
Phase Margin vs. Load Capacitance
(Supply Voltage)

V_{IN}=-30dBm, G_V=40dB, R_T=50Ω, R_F=10kΩ, R_G=100Ω, Ta=25°C



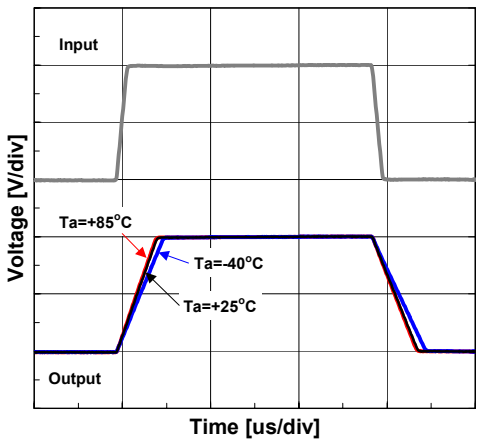
Pulse Response
(Load Capacitance, V^+/V^-=±2.5V)

V^+/V^-=±2.5V, V_{IN}=1Vp-p, A_V=+1, R_L=10kΩ, Ta=25°C



Pulse Response
(Temperature, V^+/V^-=±2.5V)

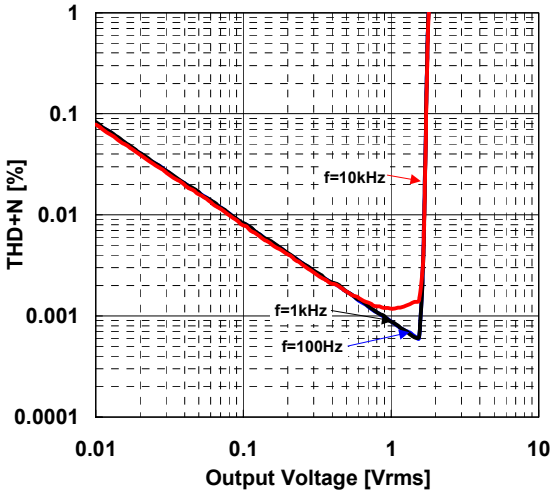
V^+/V^-=±2.5V, V_{IN}=1Vp-p, A_V=+1, R_L=10kΩ, C_L=10pF



■ TYPICAL CHARACTERISTICS

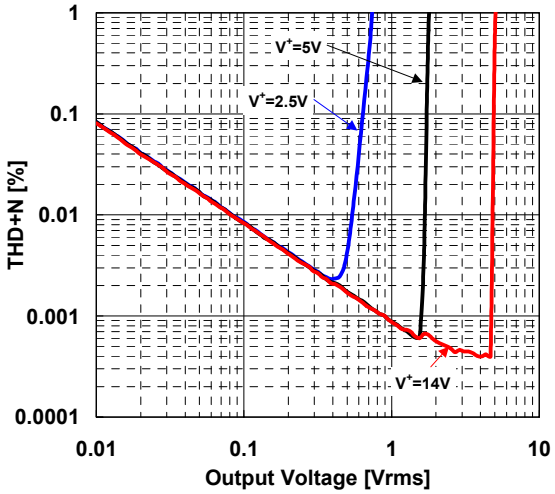
THD+N vs. Output Voltage (Frequency)

V^+=5V, A_V=+2, R_S=600Ω, R_F=5kΩ, R_G=5kΩ,
BW=10Hz~80kHz, Ta=25°C



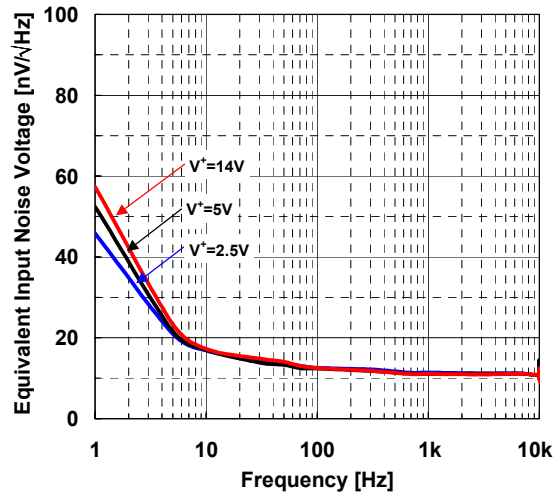
THD+N vs. Output Voltage (Supply Voltage)

f=1kHz, A_V=+2, R_S=600Ω, R_F=5kΩ, R_G=5kΩ,
BW=10Hz~80kHz, Ta=25°C



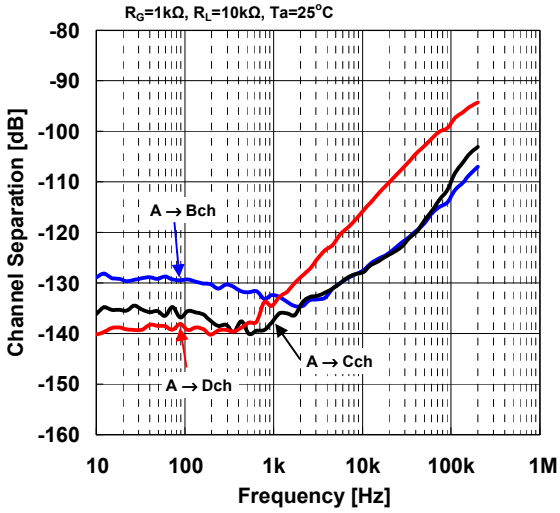
Equivalent Input Noise Voltage vs. Frequency (Supply Voltage)

G_V=60dB, R_T=600Ω, R_F=100kΩ, R_G=100Ω, Ta=25°C



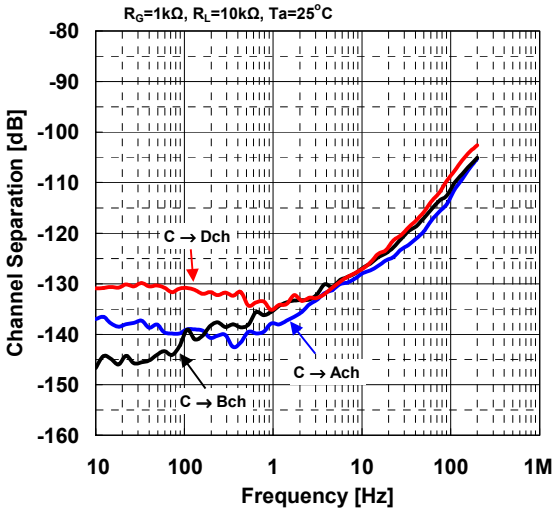
Channel Separation vs. Frequency

V^+=5V, Ach Input, V_O=1.5Vrms, G_V=40dB, R_F=100kΩ,
R_G=1kΩ, R_L=10kΩ, Ta=25°C



Channel Separation vs. Frequency

V^+=5V, Cch Input, V_O=1.5Vrms, G_V=40dB, R_F=100kΩ,
R_G=1kΩ, R_L=10kΩ, Ta=25°C



■ **MEMO**